NSN 5961-01-173-1831

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-173-1831 **Inclosure Material:** Plastic **Overall Length:** Between 0.425 inches and 0.435 inches **Terminal Length:** Between 0.595 inches and 0.655 inches **Overall Height:** Between 0.295 inches and 0.305 inches **Overall Width:** Between 0.095 inches and 0.105 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage and 50.0 peak gate voltage and 2.0 on-state voltage, peak and 2.5 peak gate trigger voltage **Current Rating Per Characteristic:** 4.00 amperes drain current horsepower metric and 30.00 amperes emitter current, dc absolute and 2.00 milliamperes forward current, total rms and 20.00 milliamperes repetitive peak forward current torr **Power Rating Per Characteristic:** 10.0 watts any acceptable blank and 0.5 watts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0